INTERNATIONAL SEARCH REPORT

IB2004/051458

A. CLASSIFICATION OF SUBJECT MATTER IPC 7 H01L31/032 H01L31/18

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

IPC 7 HO1L

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

EPO-Internal, WPI Data, PAJ, INSPEC

Category °	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	KUSHIYA K ET AL: "The role of Cu(InGa)(SeS)2 surface layer on a graded band-gap Cu(InGa)Se2 thin-film solar cell prepared by two-stage method" 25TH IEEE PHOTOVOLTAIC SPECIALISTS CONFERENCE, 13 May 1996 (1996-05-13), - 17 May 1996 (1996-05-17) pages 989-992, XP010208318 WASHINGTON, DC the whole document	1-71

Further documents are listed in the continuation of box C.	Patent family members are listed in annex.
Special categories of cited documents: A' document defining the general state of the art which is not considered to be of particular relevance E' earlier document but published on or after the international filling date L' document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) O' document referring to an oral disclosure, use, exhibition or other means P' document published prior to the International filling date but later than the priority date claimed	"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention "X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art. "&" document member of the same patent family
Date of the actual completion of the international search 30 June 2005	Date of mailing of the International search report 12/07/2005
Name and mailing address of the ISA European Patent Office, P.B. 5818 Patentlaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo nl, Fac. (+31-70) 340-3016	Authorized officer Voignier, V

INTERNATIONAL SEARCH REPORT

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	182004/051458					
Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.					
NAGOYA Y ET AL: "Role of incorporated sulfur into the surface of Cu(InGa)Se2 thin-film absorber" SOLAR ENERGY MATERIALS AND SOLAR CELLS, ELSEVIER SCIENCE PUBLISHERS, AMSTERDAM, NL, vol. 67, no. 1-4, March 2001 (2001-03), pages 247-253, XP004224767 ISSN: 0927-0248 cited in the application the whole document	1-71					
KUSHIYA K ET AL: "Formation Chemistry of polycrystalline Cu(InGa)Se2 thin-film absorber perpared by selenization of Cu-Ga/In stacked precursor layers with H2Se gas" MATERIALS RESEARCH SOCIETY SYMPOSIUM PROCEEDINGS, MATERIALS RESEARCH SOCIETY, PITTSBURG, PA, US, vol. 426, 8 April 1996 (1996-04-08), pages 177-182, XP002092402 ISSN: 0272-9172 the whole document	1-71					
KUSHIYA K ET AL COMMISSION OF THE EUROPEAN COMMUNITIES: "DEVELOPMENT OF Cu(InGa)Se2 THIN-FILM SOLAR CELLS WITH Zn-COMPOUND BUFFER" 13TH. E.C. PHOTOVOLTAIC SOLAR ENERGY CONFERENCE. NICE, FRANCE, OCT. 23, vol. Vol. 2 OF 2. CONF. 13, 23 October 1995 (1995-10-23), pages 2016-2019, XP001140334 ISBN: 0-9521452-7-8 the whole document	1-71					
US 5 436 204 A (ALBIN ET AL) 25 July 1995 (1995-07-25) column 3, line 60 - column 7, line 48	1-71					
	NAGOYA Y ET AL: "Role of incorporated sulfur into the surface of Cu(InGa)Se2 thin-film absorber" SOLAR ENERGY MATERIALS AND SOLAR CELLS, ELSEVIER SCIENCE PUBLISHERS, AMSTERDAM, NL, vol. 67, no. 1-4, March 2001 (2001-03), pages 247-253, XP004224767 ISSN: 0927-0248 cited in the application the whole document KUSHIYA K ET AL: "Formation Chemistry of polycrystalline Cu(InGa)Se2 thin-film absorber perpared by selenization of Cu-Ga/In stacked precursor layers with H2Se gas" MATERIALS RESEARCH SOCIETY SYMPOSIUM PROCEEDINGS, MATERIALS RESEARCH SOCIETY, PITTSBURG, PA, US, vol. 426, 8 April 1996 (1996-04-08), pages 177-182, XP002092402 ISSN: 0272-9172 the whole document KUSHIYA K ET AL COMMISSION OF THE EUROPEAN COMMUNITIES: "DEVELOPMENT OF Cu(InGa)Se2 THIN-FILM SOLAR CELLS WITH Zn-COMPOUND BUFFER" 13TH. E.C. PHOTOVOLTAIC SOLAR ENERGY CONFERENCE. NICE, FRANCE, OCT. 23, vol. VOL. 2 OF 2. CONF. 13, 23 October 1995 (1995-10-23), pages 2016-2019, XP001140334 ISBN: 0-9521452-7-8 the whole document US 5 436 204 A (ALBIN ET AL) 25 July 1995 (1995-07-25)					

INTERNATIONAL SEARCH REPORT

IB2004/051458

Patent document cited in search report		Publication date	Patent family member(s)		Publication date
US 5436204 A		25-07-1995	US 5356839 A		
			AU	3274795 A	14-03-1996
			EP	0724775 Al ⁻	07-08-1996
			JP	9506475 T	24-06-1997
			WO	9606454 A1	29-02-1996
			ΑU	6628194 A	08-11-1994
			DE	69425255 D1	17-08-2000
			DE	69425255 T2	15-03-2001
			ΕP	0694209 A1	31-01-1996
			JP	3258667 B2	18-02-2002
			JP	10513606 T	22-12-1998
			JP	3130943 B2	31-01-2001
			JP	8510359 T	29-10-1996
			WO	9424696 A1	27-10-1994
			WO	9625768 A1	22-08-1996
			US	5441897 A	15-08-1995